



September 11, 2015

Dear Valued Customer:

Re: Change of Name of International Rectifier Corporation

On January 13, 2015, Infineon Technologies AG acquired International Rectifier Corporation. As a follow-up to the acquisition, effective as of October 1, 2015 the name of International Rectifier Corporation (IR) will be changed to

Infineon Technologies Americas Corp.

This is a change in name only, and does not reflect a change in operations, facilities, entity, tax ID or registered address.

- You will continue to be served by your current account manager.
- Your checks should be mailed to the same address, and your wire transfers/ACH should be sent to the same bank account.
- Your shipments will continue to come from the same site.
- You will still deal with the same personnel you currently deal with.

As our customer you are very important to us, and we would like to make this transition as seamless as possible. Should you have any questions or concerns regarding the name change, please contact your IR representative.

We look forward to our strong continued business relationship.

Sincerely,

International Rectifier Corporation

Rainer Matern
Senior Director Accounting,
Controlling & Business Operations

Michael Cortez
Director
Accounting & Treasury

Product / Process Change Notification



Date: Friday, November 06, 2015
PCR Reference: 729
PCN Reference: 729-PCN180-Public

To Our Value Customer:

As always we appreciate your use of Infineon Technologies semiconductor products. Our commitment to customer satisfaction and continuous improvement is demonstrated by our change plans to enhance capacity, quality and reliability. This notice is to inform you of the following change:

We would like to express our sincere appreciation for your cooperation regarding the following changes, and Infineon Technologies will work closely with you to support your requirements during this transition.

Type of Change Notification:

Wafer Fab and Wafer test site

Description of Change:

Gen 10.7 MOSFET- Automotive

Products currently manufactured and wafer-level tested in the IFX Newport, South Wales UK (Fab11) eight inch facility will be transferred to the VIS Hsinchu, Taiwan (Fab2) eight inch wafer fab and subcontract facilities.

Samples with the changes are available upon request

Reason for the Change:

As part of a manufacturing consolidation plan announced in March 2014, Infineon indicated that it would be closing the Fab11 facility and transferring the production capability for certain parts to foundries.

Effect Date:

Wednesday, May 04, 2016

Infineon Technologies will consider this change approved and will implement it by the effective date unless specific conditions of acceptance or data requests are provided in writing within 30 days of receipt of this notice. Please submit conditions of acceptance and data requests to the PCN coordinator listed at the end of this notice.

Impact of Change:

No changes to form, fit, or function. The package outline remains the same. Datasheet specifications will not be changed. The package bill of material and the location for assembly and final test will not change.

Method of Identifying Changed Product:

Date Code and Lot Code Information

Products Affected:

| IR Part | Description |
|-------------|--|
| AUIRF1018E | Automotive MOSFET 60V, 79A, 8.4 mOhm, 46 nC Qg, DPak |
| AUIRF1018ES | Automotive MOSFET 60V, 79A, 8.4 mOhm, 46 nC Qg, DPak |
| AUIRFB3806 | Automotive MOSFET 60V, 43A, 15.8 mOhm, 22 nC Qg, TO220 |

| | |
|--------------------|--|
| AUIRFP4110 | |
| AUIRFR1018E | 60V 79.000A AUTO D-PAK |
| AUIRFR3806 | Automotive Q101 60V Single N-Channel HEXFET Power MOSFET in a D-Pak Package |
| AUIRFR3806TRL | Automotive Q101 60V Single N-Channel HEXFET Power MOSFET in a D-Pak Package |
| AUIRFR4620 | Automotive MOSFET 200V, 24A, 78 mOhm, 25 nC Qg, DPak |
| AUIRFR4620TRL | Automotive MOSFET 200V, 24A, 78 mOhm, 25 nC Qg, DPak |
| AUIRFS3107 | Automotive MOSFET 75V, 230A, 3 mOhm, 160 nC Qg, D2Pak |
| AUIRFS3107-7P | Automotive MOSFET 75V, 260A, 2.6 mOhm, 160 nC Qg, D2Pak-7P |
| AUIRFS3107-7TRL | Automotive MOSFET 75V, 260A, 2.6 mOhm, 160 nC Qg, D2Pak-7P |
| AUIRFS3107TRL | Automotive MOSFET 75V, 230A, 3 mOhm, 160 nC Qg, D2Pak |
| AUIRFS3306 | Automotive MOSFET 60V, 160A, 4.2 mOhm, 85 nC Qg, D2Pak |
| AUIRFS3306TRL | Automotive MOSFET 60V, 160A, 4.2 mOhm, 85 nC Qg, D2Pak |
| AUIRFS3806 | Automotive MOSFET 60V, 43A, 15.8 mOhm, 22 nC Qg, D2PAK |
| AUIRFS4010 | Automotive MOSFET 100V, 170A, 4.7 mOhm, 143 nC Qg, D2Pak |
| AUIRFS4010-7P | Automotive MOSFET 100V, 190A, 4 mOhm, 150 nC Qg, D2Pak-7P |
| AUIRFS4010-7TRL | Automotive MOSFET 100V, 190A, 4 mOhm, 150 nC Qg, D2Pak-7P |
| AUIRFS4010TRL | Automotive MOSFET 100V, 170A, 4.7 mOhm, 143 nC Qg, D2Pak |
| AUIRFS4410Z | Automotive MOSFET 100V, 97A, 9mOhm, 87 nC Qg, D2Pak |
| AUIRFS4410ZTRL | Automotive MOSFET 100V, 97A, 9mOhm, 87 nC Qg, D2Pak |
| AUIRFSL4010 | Automotive MOSFET 100V, 170A, 4.7 mOhm, 143 nC Qg, D2Pak |
| AUIRFSL4010-313 | |
| AUIRFSL4010-313TRL | |
| AUIRLS3034 | Automotive Logic Level MOSFET 40V, 343A, 1.7 mOhm, 108 nC Qg, D2Pak |
| AUIRLS3034-7P | Automotive Logic Level MOSFET 40V, 380A, 1.4 mOhm, 120 nC Qg, D2Pak-7P |
| AUIRLS3034-7TRL | Automotive Logic Level MOSFET 40V, 380A, 1.4 mOhm, 120 nC Qg, D2Pak-7P |
| AUIRLS3034TRL | Automotive Logic Level MOSFET 40V, 343A, 1.7 mOhm, 108 nC Qg, D2Pak |
| AUIRLS3036 | Automotive Logic Level MOSFET 60V, 270A, 2.4 mOhm, 91 nC Qg, D2Pak |
| AUIRLS3036-7P | Automotive Logic Level MOSFET 60V, 300A, 1.9 mOhm, 110 nC Qg, D2Pak-7P |
| AUIRLS3036-7TRL | Automotive Logic Level MOSFET 60V, 300A, 1.9 mOhm, 110 nC Qg, D2Pak-7P |
| AUIRLS3036TRL | Automotive Logic Level MOSFET 60V, 270A, 2.4 mOhm, 91 nC Qg, D2Pak |
| AUIRLS4030 | Automotive Logic Level MOSFET 100V, 180A, 4.3 mOhm, 87 nC Qg, D2PakAutomotive Logic Level MOSFET 100V, 180A, 4.3 mOhm, 87 nC Qg, D2Pak |
| AUIRLS4030-7P | Automotive Logic Level MOSFET 100V, 190A, 3.9 mOhm, 93 nC Qg, D2Pak-7P |
| AUIRLS4030-7TRL | Automotive Logic Level MOSFET 100V, 190A, 3.9 mOhm, 93 nC Qg, D2Pak-7P |
| AUIRLS4030TRL | Automotive Logic Level MOSFET 100V, 180A, 4.3 mOhm, 87 nC Qg, D2Pak |
| AUIRLSL3036 | Automotive Logic Level MOSFET 60V, 270A, 2.4 mOhm, 91 nC Qg, D2Pak |

Qualification:

Parts passed all the reliability testing requirements. Reliability qualification report is available upon request.

Supporting Data Availability:

Contact Infineon Technologies for supporting data on this change.

Contact Information:

| CONTACT TYPE | NAME | PHONE | EMAIL |
|-----------------|------------|-------------------|--|
| PCN Coordinator | Mark Ogden | +001-951-375-2334 | Mark.Ogden@infineon.com |